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JAPANESE PATENT OFFICE

PATENT ABSTRACTS OF JAPAN

(11) Publication number: 2000223012 A

(43) Date of publication of application: 11.08.2000

(51) Int. Cl H01J 9/02  
B01J 19/08, C01B 31/02, H01J 1/304

(21) Application number: 11059142  
(22) Date of filing: 31.01.1999

(71) Applicant: FUTABA CORP  
(72) Inventor: TAKIGAWA HIROSHI  
SAKAKIBARA KENJU  
ITO SHIGEO

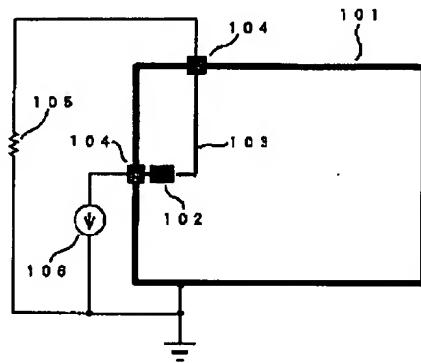
(54) ELECTRON EMITTING SOURCE AND  
MANUFACTURE THEREOF

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(57) Abstract:

PROBLEM TO BE SOLVED: To provide an easy manufacturing method of an electron emitting source.

SOLUTION: A negative electrode 102 is locally heated by carrying an arc electric current of DC 100 A and arc-discharging for a second in a chamber 101 of an He atmosphere under a pressure of 1 Pa. Negative electrode material for forming the negative electrode 102 is scattered and particles with a lot of carbon nanotubes formed on the surface are generated. The particles are collected and used as an emitter of the electron emitting source.





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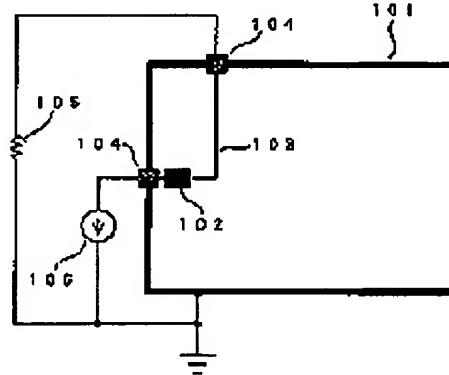
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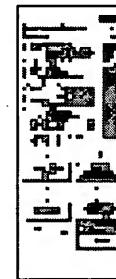
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### >Title: JP2000223012A2: ELECTRON EMITTING SOURCE AND MANUFACTURE THEREOF

Derwent Title: Manufacture of source for electron emission, involves heating particle formation material at predetermined atmosphere and adhering the formed particle to a substrate [\[Derwent Record\]](#)



Country: JP Japan

Kind: A2 Document Laid open to Public inspection

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Published / Filed: 2000-08-11 / 1999-01-31

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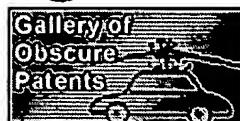
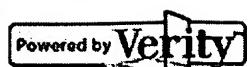
Family: None

Forward References:

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PDF	Patent	Pub.Date	Inventor	Assignee	Title
	<a href="#">US6848962</a>	2005-02-01	Kitamura; Shin	Canon Kabushiki Kaisha	Electron-emitting device, electron image-forming apparatus, and producing electron-emitting device electron-emitting apparatus

Other Abstract Info: CHEMABS 133(12)171172B CHEMABS 133(12)171172B DERABS C2000-596841 DE C2000-596841



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